

STP24DP05

24-bit constant current LED sink driver with output error detection

Features

- Low voltage power supply down to 3 V
- 8 x 3 constant current output channels
- Adjustable output current through external resistors
- Short and open output error detection
- Serial data IN/Parallel data OUT
- Shift register data flow registers control
- Accepts 3.3 V and 5 V micro driver
- Output current: 5-80 mA
- 25 MHz clock frequency
- High thermal efficiency package

Description

The STP24DP05 is a monolithic, low voltage, low current power 24-bit shift register designed for LED panel displays. The device contains a 8 x 3-bit serial-in, parallel-out shift register that feeds a 8 x 3-bit D-type storage register. In the output stage, twenty-four regulated current sources were designed to provide 5-80 mA constant current to drive the LEDs.

The 8x3 shift registers data flow sequence order can be managed with two dedicated pins.

The STP24DP05 has a dedicated pin to activate the outputs with a sequential delay, that will prevent inrush current during outputs turn-ON.

The device detection circuit checks 3 different conditions that can occur on the output line: short to GND, short to $V_{\rm O}$ or open line.



The data detection results are loaded in the shift registers and shifted out via the serial line output.

The detection functionality is activated with a dedicated pin or as alternative, through a logic sequence that allows the user to enter or exit from detection mode.

Through three external resistors, users can adjust the output current for each 8-channel group, controlling in this way the light intensity of LEDs.

The STP24DP05 guarantees a 20 V output driving capability, allowing users to connect more LEDs in series.

The high clock frequency, 25 MHz, makes the device suitable for high data rate transmission.

The 3.3 V of voltage supply is useful for applications that interface any micro from 3.3 V.

Table 1.Device summary

Order code	Package	Packaging
STP24DP05BTR	TQFP48	Tape and reel

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1 Summary description

Table 2. Current accuracy

Output voltage	Typical current accuracy		Output current	V _{DD}	Temperature
output voltage	Between bits	Between ICs	output ourrent	- 00	remperature
≥ 1.0 V	±3%	±6%	\geq 15 to 80 mA	3.3 V to 5 V	25 °C
≥ 0.2 V	±6%	±6%	5 to 15 mA	0.0 V 10 0 V	20 0

1.1 Pin connection and description

Figure 1. Pin connection



Pin N°	Symbol	Name and function
1, 7, 12, 25, 30, 36	GND	Ground terminal
2	SDI	Serial data input
		· · · ·
35	SDO	Serial data output
4	CLK	Clock for serial data
3	LE\DM	Data latch in both SH register
5	DM	Detection mode pin
13, 16, 19, 22, 39, 42, 45, 48	R1 - 8	8 channel LED driver outputs
8	TF	Thermal flag (open drain)
29	EF	Error detection flag (open drain)
9	DG	Gradual delay
15, 17, 20, 23, 37, 40, 43, 46	B1 - 8	8 channel LED driver outputs
32	OE-B	Output enable for B1 - 8
33	OE-G	Output enable for G1 - 8
34	OE-R\DM	Output enable for R1 - 8
28	REXTR	Control outputs R1 - 8
27	REXTG	Control outputs G1 - 8
26	REXTB	Control outputs B1 - 8
14, 18, 21, 24, 38, 41, 44, 48	G1 - 8	8 channel LED driver outputs
10	DF0	Data banks flow bit 0
11	DF1	Data banks flow bit 1
31	VDD	Supply voltage terminal
l		

Table 3. Pin description



2 Electrical ratings

2.1 Absolute maximum ratings

Stressing the device above the rating listed in the "absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE program and other relevant quality documents.

Symbol	Parameter	Value	Unit
V _{DD}	Supply voltage - digital	0 to 7	V
V _O	Output voltage - LED driver	-0.5 to 20	V
V _{TF} and V _{ER}	Open drain absolute voltage	0 to 7	V
Ι _Ο	Output current - LED driver	80	mA
VI	Input voltage - digital	-0.4 to V _{DD} +0.4	V
I _{GND}	GND terminal current	2000	mA
f _{CLK}	Clock frequency	30	MHz

 Table 4.
 Absolute maximum ratings

2.2 Thermal data

Table 5. Thermal data

Symbol	Parameter	Value	Unit
T _{OPR}	Operating temperature range	-40 to 125	°C
T _{STG}	Storage temperature range	-40 to 150	°C
R _{thJC}	Thermal resistance junction-case	25	°C/W



2.3 Recommended operating conditions

Table 6.	Recommended operating conditions					
Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
V_{DD}	Supply voltage		3.0		5.5	V
Vo	Output voltage				20	V
Ι _Ο	Output current	OUTn	5		80	mA
I _{OH}	Output current	SERIAL-OUT		+10		mA
I _{OL}	Output current	SERIAL-OUT		-10		mA
V _{IH}	Input voltage		0.7V _{DD}		V _{DD} +0.3	V
V _{IL}	Input voltage		-0.3		0.3V _{DD}	V
t _{wLAT}	LE pulse width		15			ns
t _{wCLK}	CLK pulse width		15			ns
t _{wEN}	OE pulse width	V _{DD} = 3.0 V to 5.0 V	150			ns
t _{SETUP(D)}	Setup time for DATA	$v_{DD} = 3.0 \ v \ 10 \ 5.0 \ v$	15			ns
t _{HOLD(D)}	Hold time for DATA]	5			ns
t _{SETUP(L)}	Setup time for LATCH		10			ns
f _{CLK}	Clock frequency	Cascade operation (1)			25	MHz

 Table 6.
 Recommended operating conditions

1. If the device is connected in cascade, it may not be possible achieve the maximum data transfer. Please consider the timings carefully.

3 Electrical characteristics

Table 7. Electrical characteristics

 $(V_{DD} = 3.3 \text{ V to 5 V}, T = 25 \text{ °C}, \text{ unless otherwise specified.})$

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
V _{IH}	Input voltage high level		0.7V _{DD}		V _{DD}	V
V _{IL}	Input voltage low level		GND		0.3V _{DD}	V
I _{OH}	Output leakage current	V _{OH} = 20 V			10	μA
V _{OL}	Output voltage (Serial-OUT)	I _{OL} = 1 mA			0.4	v
V _{OH}	Output voltage (Serial-OUT)	I _{OH} = -1 mA	V _{DD} -0.4V			V
I _{OL1}		$V_O = 0.3 \text{ V}, \text{ R}_{\text{EXT}} = 2 \text{ k}\Omega,$ $I_O = 10 \text{ mA}$		20		mA
I _{OL2}	Output current	$V_O = 0.3 \text{ V}, \text{ R}_{\text{EXT}} = 1 \text{ k}\Omega,$ $I_O = 20 \text{ mA}$		80		mA
I _{OL3}		$\label{eq:VO} \begin{array}{l} V_O = 0.3 \text{V}, \ \text{R}_{\text{EXT}} = 250 \ \Omega, \\ \text{I}_O = 80 \ \text{mA} \end{array}$		80		mA
ΔI_{OL1}		$V_O = 0.3 \text{ V}, \text{ R}_{\text{EXT}} = 2 \text{ k}\Omega,$ $I_O = 10 \text{ mA}$		± 2	± 3	%
ΔI_{OL2}	Output current error among the channels (All outputs ON)	$V_O = 0.3 \text{ V}, \text{ R}_{\text{EXT}} = 1 \text{ k}\Omega,$ $I_O = 20 \text{ mA}$		± 2	± 3	%
ΔI_{OL3}	($\label{eq:VO} \begin{array}{l} V_{O} = 0.3 V, \ R_{EXT} = 250 \ \Omega, \\ I_{O} = 80 \ mA \end{array}$		± 2	± 3	%
R _{SIN(up)}	Pull-up resistor		300	600	800	kΩ
R _{SIN(down)}	Pull-down resistor		300	400	500	kΩ
LE _(up) DG _(up) OE-R\ DM (up) OE-G (up) OE-B (up) DF0 DF1	Pull-up resistor		300	400	500	kΩ
I _{DD(OFF1)}	- Supply current (OFF)	R _{EXT} = 1 kΩ OUT 0 to 15 = OFF		9	12	
I _{DD(OFF2)}		R _{EXT} = 250 Ω OUT 0 to 15 = OFF		32	40	mA
I _{DD(ON1)}	- Supply current (ON)	R _{EXT} = 1 kΩ OUT 0 to 15 = ON		13	18	
I _{DD(ON2)}		R _{EXT} = 250 Ω OUT 0 to 15 = ON		35	40	



Table 7. Electrical characteristics

 $(V_{DD} = 3.3 \text{ V to 5 V}, T = 25 \text{ °C}, \text{ unless otherwise specified.})$

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
Thermal	Thermal protection			170		°C
V _{TF}	Output voltage				5	V
I _{TF}	Output current	V _{TF} @ 1 V	20			mA
V _{EF}	Output voltage				5	V
I _{EF}	Output current	V _{EF} @ 1 V	20			mA

Table 8.Switching characteristics ($V_{DD} = 5 V$, T = 25 °C, unless otherwise specified.)

Symbol	Parameter	Т	est conditions	;	Min	Тур	Max	Unit
+	Propagation delay time,			V _{DD} = 3.3 V		62	100	200
t _{PLH1}	$CLK-\overline{OUTn}$, $LE = H$, $\overline{OE} = L$			V _{DD} = 5 V		38	60	ns
t	Propagation delay time,		V _{DD} = 3.3 V		67	107	ns	
t _{PLH2}	$LE-\overline{OUTn}, \overline{OE} = L$			$V_{DD} = 5 V$		44	60	115
t _{PLH3}	Propagation delay time,			V _{DD} = 3.3 V		65	83	ns
4PLH3	OE-OUTn, LE = H			$V_{DD} = 5 V$		38	45	110
t _{PLH}	Propagation delay time,			V _{DD} = 3.3 V	14	22	36	ns
PLH	CLK-SDO			V _{DD} = 5 V	9	14	23	110
	Propagation delay time, CLK-OUTn, LE = H,			V _{DD} = 3.3 V		46	70	
t _{PHL1}	$\overline{OE} = L$	V _{DD} = 3.3 V V _{II} = GND		$V_{DD} = 5 V$		39	50	ns
+	Propagation delay time,	l _O = 20 mA	$V_{L} = 3.0 V$	V _{DD} = 3.3 V		51	76	ns
t _{PHL2}	$\overline{\text{LE-OUTn}}, \overline{\text{OE}} = L$	$R_{EXT} = 1 \ k\Omega$	$R_L = 60 \Omega$	$V_{DD} = 5 V$		46	55	115
t	Propagation delay time,			V _{DD} = 3.3 V		41	45	ns
t _{PHL3}	OE-OUTn, LE = H			$V_{DD} = 5 V$		33	39	115
t _{PHL}	Propagation delay time,			V _{DD} = 3.3 V	15	24	38	ns
YPHL	CLK-SDO			$V_{DD} = 5 V$	9	15	24	115
	Output rise time			V _{DD} = 3.3 V		33	57	
t _{ON}	10~90% of voltage waveform			$V_{DD} = 5 V$		17	27	ns
	Output fall time			V _{DD} = 3.3 V		24	34	
t _{OFF}	90~10% of voltage waveform			V _{DD} = 5 V		25	37	ns
t _r	CLK rise time (1)						5000	ns
t _f	CLK fall time ⁽¹⁾						5000	ns

1. In order to achieve high cascade data transfer, please consider tr/tf timings carefully.



4 Block diagram

Figure 2. Block diagram



5 Equivalent circuit and outputs





Figure 4. LE\DM terminal



Figure 5. CLK, SDI terminal





Figure 6. SDO terminal



Figure 7. TF and EF





6 Timing diagrams



Note:

The latches circuit holds data when the LE terminal is low.

- 1 When LE\DML terminal is at high level, latch circuit hold the data it passes from the input to the output.
- 2 When either $\overline{OE-R\backslash DM}$, $\overline{OE-G}$, $\overline{OE-B}$ terminals are at low level, output terminals $R\backslash G\backslash B1$ to $R\backslash G\backslash B8$ respond to the data, either ON or OFF.
- 3 When either OE-R\DM, OE-G, OE-B terminals are at high level, it switches off all the data on the output terminal R\G\B1 to R\G\B8.





Figure 9. Clock, serial-in, serial-out





Figure 10. Clock, serial-in, latch, enable, outputs







7 Feature description

7.1 DG: gradual outputs delay

This feature prevents large inrush current and reduces the bypass capacitors.

The fixed delay time can be activated with DG = LOW and the typical output delay is 20 ns for each group of 8 outputs R, G, B. Eg: R1, G1, B1 has no delay, R2, G2, B2 has 20 ns delay and R3, G3, B3, has 40 ns delay, etc.

R2 **R7 R8 R1** R3 R4 R5 R6 Delay time (ns) from $\downarrow \overline{OExx}$ G1 G2 G3 G7 G8 G4 G5 G6 **B**4 **B**5 **B**7 **B1 B2 B**3 **B6 B8** DG = 00 30 60 90 120 150 180 200 DG = 1 0 0 0 0 0 0 0

Table 9. Typical gradual delay time table

7.2 Error detection condition

Table 10. Detection conditions (V_{DD} = 3.3 to 5 V, I_O = 20 mA, t_A = 25 °C)

SW-1 Open or SW-3b	Open line or output short to GND detected	=> $I_{ODEC} \le 0.4 \text{ x } I_O$	No error detected	=> $I_{ODEC} \ge 0.35 \text{ x } I_O$
SW-2 Closed or SW-3a	Short on LED or short to V-LED detected	=> V _O ≥ 2.6 V	No error detected	=> V _O ≤ 2.4 V

Note:

 I_O = the output current programmed by the R_{EXT}

*I*_{ODEC} = the detected output current in detection mode

Table 11.	Typical current threshold values to detect LED open line
-----------	----------------------------------------------------------

lset (mA)	Rext (Ω)	Typ. out current detection (mA)
5	3920	1.28
10	1960	2.45
20	980	7.4
50	386	17
80	241	27



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Figure 12. Detection circuit



7.3 Phase one: "entering in detection mode"

From the "normal mode" condition the device can switch to the "error detection mode" by a DM PIN set to LOW or a logic sequence on the $\overline{\text{OE-R/DM}}$ and LE/DM pins as showed in the following table and diagram:



Figure 13. EDM timing diagram using DM pin

Table 12.	SPI sequence to enter in detection mode - truth table
-----------	-------------------------------------------------------

CLK	1 °	2 °	3 °	4 °	5°
OE-R/DM	Н	L	Н	Н	Н
LE/DM	L	L	L	Н	L



Figure 14. SPI sequence to enter in detection mode - time diagram

After these five CLK cycles the device goes into the "error detection mode" and at the 6th rise front of CLK the SDI data are ready for the sampling.

7.4 Phase two: "error detection"

The eight data bits must be set "1" in order to set ON all the outputs during the detection. The data are latched by LE/DM and after that the outputs are ready for the detection process. When the micro controller switches the OE-R/DM to LOW, the device drives the LEDs in order to analyze if an OPEN or SHORT condition has occurred.



Figure 15. Detection diagram

The LEDs status will be detected at least in 1 microsecond and after this time the microcontroller sets OE-R/DM in HIGH state and the output data detection result will go to the microprocessor via SDO.

Detection mode and normal mode use both the same format data. As soon as all the detection data bits are available on the serial line, the device may go back to normal mode of operation.



7.5 Phase three: "resuming to normal mode"

In order to re-enter in normal mode either the LE\DML pin or the sequence showed in the following table and diagram can be used:

CLK	1 °	2 °	3 °	4 °	5°
OE-R/DM	Н	L	Н	Н	Н
LE/DM	L	L	L	L	L

 Table 13.
 SPI sequence to resume in normal mode - truth table

Note:

For proper device operation the "entering in detection" sequence must be followed by a "resume mode" sequence, it is not possible to insert consecutive equal sequence.

7.6 Shift registers data flow control

The 8x3 shift registers have a default RGB sequence serial data flow as showed on block diagram *Figure 2.*

The data can be redirected by DF0 and DF1 pins, these pins change the order of the data flow according to the following table:

Table 14.	Shifter register d	ata flow control	
Sequence		DF0	

Sequence	DF0	DF1
BGR	1	1
BGR	0	1
RGB	1	0
GBR	0	0



7.7 EFLAG/TFLAG - output detection and overtemperature monitoring

The open-drain output EFLAG and TFLAG are used to report the STP24DP05 error flags. During normal operating conditions, the voltage on EFLAG/TFLAG is pulledup through an external resistor. When an error is detected, the internal switch is turned on, to GND.







8 Typical application schematic







9 Typical characteristics



Figure 18. Typical external resistor values vs output current capabilities

Table 15. Typical external resistor values vs output current capabilitie	Table 15.	xternal resistor values vs output current capabilities
--------------------------------------------------------------------------	-----------	--------------------------------------------------------

Iset	5 mA	10 mA	20 mA	50 mA	80 mA
Rext (Ω)	4210	2050	1000	400	249

Figure 19. Typical dropout voltage vs output current



Table 16. Typical dropout voltage vs output current

	<u>, , , , , , , , , , , , , , , , , , , </u>		
lset	Rext (Ω)	Avg (mV) @ 3.3 V	Avg (mV) @ 5.0 V
5	4210	59	41
10	2050	130	90
20	1000	201	180
50	400	500	480
80	249	810	790



10 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com





TQFP48 MECHANICAL DATA							
DIM.		mm.			inch		
DIN.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А			1.6			0.063	
A1	0.05		0.15	0.002		0.006	
A2	1.35	1.40	1.45	0.053	0.055	0.057	
В	0.17	0.22	0.27	0.007	0.009	0.011	
С	0.09		0.20	0.0035		0.0079	
D		9.00			0.354		
D1		7.00			0.276		
D3		5.50			0.216		
е		0.50			0.020		
E		9.00			0.354		
E1		7.00			0.276		
E3		5.50			0.216		
L	0.45	0.60	0.75	0.018	0.024	0.030	
L1		1.00			0.039		
К	0°	3.5°	7°	0°	3.5°	7°	

Figure 20. TQFP48 mechanical data





5114	mm.				inch	
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
Ν	60			2.362		
Т			22.4			0.882
Ao	9.5		9.7	0.374		0.382
Во	9.5		9.7	0.374		0.382
Ko	2.1		2.3	0.083		0.091
Po	3.9		4.1	0.153		0.161
Р	11.9		12.1	0.468		0.476
A						N V

Po

C

Ao

 \bigcirc

Ko

 \bigcirc

d

Ρ

Note: Drawing not in scale

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Π

Figure 21. TQFP48 tape and reel

Βо



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11 Revision history

 Table 17.
 Document revision history

Date	Revision	Changes
19-Apr-2008	1	First release



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